

TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

## TD62786AP, TD62786F, TD62786AF TD62787AP, TD62787F, TD62787AF

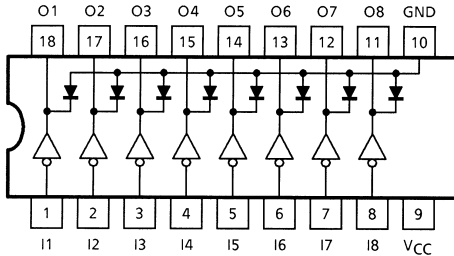
### 8CH HIGH-VOLTAGE SOURCE DRIVER

The TD62786AP / F / AF series are eight channel hux non-inverting source current transistor array. All units feature integral clamp diodes for switching inductive loads. Applications include relay, hammer and lamp drivers.

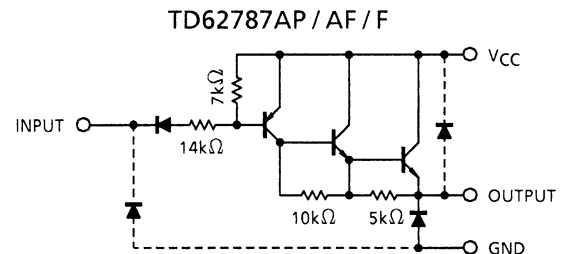
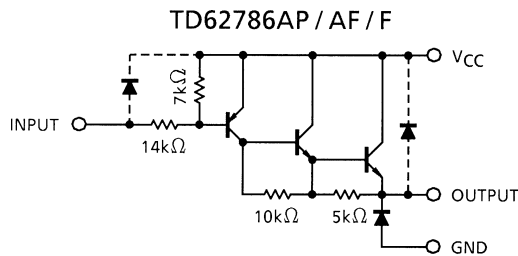
### FEATURES

- High output voltage type-AP, AF :  $V_{CE(SUS)} = 50\text{ V (Min)}$   
type-F :  $V_{CE(SUS)} = 35\text{ V (Min)}$
- Output current (single output) :  $I_{OUT} = -500\text{ mA / ch (Max)}$
- Output clamp diodes
- Single supply voltage
- Input compatible with TTL, 5 V CMOS
- Low level active input
- Package type-AP : DIP-18 pin
- Package type-F, AF: SOP-18 pin

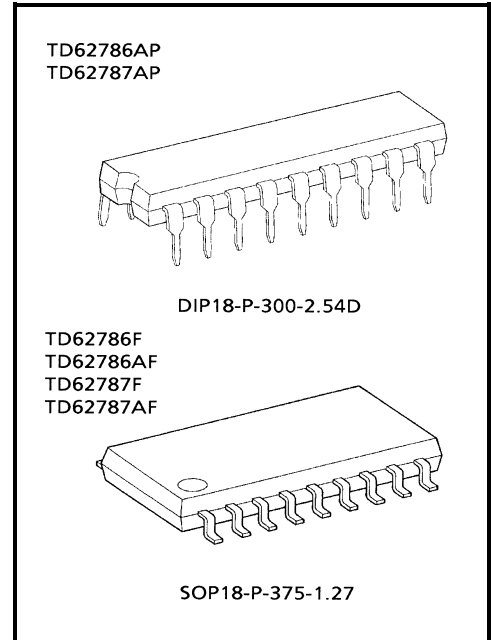
### PIN CONNECTION (TOP VIEW)



### SCHEMATICS (EACH DRIVER)



Note: The input and output parasitic diodes cannot be used as clamp diodes.



Weight  
DIP18-P-300-2.54D : 1.47 g (Typ.)  
SOP18-P-375-1.27 : 0.41 g (Typ.)

## MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC              |         | SYMBOL                            | RATING              | UNIT    |
|-----------------------------|---------|-----------------------------------|---------------------|---------|
| Supply Voltage              | AP / AF | V <sub>CC</sub> -V <sub>GND</sub> | 50                  | V       |
|                             | F       |                                   | 35                  |         |
| Output Sustaining Voltage   | AP / AF | V <sub>OUT</sub>                  | -50                 | V       |
|                             | F       |                                   | -35                 |         |
| Output Current              |         | I <sub>OUT</sub>                  | -500                | mA / ch |
| Input Voltage               |         | V <sub>IN</sub> (Note 1)          | -30~0.5             | V       |
| Input Voltage               |         | V <sub>IN</sub> (Note 2)          | V <sub>GND</sub> ~7 | V       |
| Clamp Diode Forward Current | AP / AF | V <sub>R</sub>                    | 50                  | V       |
|                             | F       |                                   | 35                  |         |
| Clamp Diode Forward Current |         | I <sub>F</sub>                    | 500                 | mA      |
| Power Dissipation           | AP      | P <sub>D</sub> (Note 3)           | 1.47                | W       |
|                             | F / AF  |                                   | 0.96                |         |
| Operating Temperature       |         | T <sub>opr</sub>                  | -40~85              | °C      |
| Storage Temperature         |         | T <sub>stg</sub>                  | -55~150             | °C      |

Note 1: Only TD62786AP / F / AF

Note 2: Only TD62787AP / F / AF

Note 3: Delated above 25°C in the proportion of 11.7 mW / °C (AP Type), 7.7 mW / °C (F, AF Type).

## RECOMMENDED OPERATING CONDITIONS (Ta = -40~85°C, V<sub>CC</sub> = 0 V)

| CHARACTERISTIC              |         | SYMBOL                            | CONDITION | MIN              | TYP. | MAX  | UNIT    |
|-----------------------------|---------|-----------------------------------|-----------|------------------|------|------|---------|
| Supply Voltage              | AP / AF | V <sub>CC</sub> -V <sub>GND</sub> | —         | —                | —    | 50   | V       |
|                             | F       |                                   | —         | —                | —    | 35   |         |
| Output Voltage              | AP / AF | V <sub>OUT</sub>                  | —         | —                | —    | -50  | V       |
|                             | F       |                                   | —         | —                | —    | -35  |         |
| Output Current              |         | I <sub>OUT</sub>                  | —         | —                | —    | -350 | mA / ch |
| Input Voltage               | TD62786 | V <sub>IN</sub>                   | —         | -30              | —    | 0    | V       |
|                             | TD62787 |                                   | —         | V <sub>GND</sub> | —    | 7    |         |
| Clamp Diode Reverse Voltage | AP / AF | V <sub>R</sub>                    | —         | —                | —    | 50   | V       |
|                             | F       |                                   | —         | —                | —    | 35   |         |
| Clamp Diode Forward Current |         | I <sub>F</sub>                    | —         | —                | —    | 350  | mA      |
| Power Dissipation           | AP      | P <sub>D</sub>                    | —         | —                | —    | 0.52 | W       |
|                             | AF / F  |                                   | —         | —                | —    | 0.35 |         |

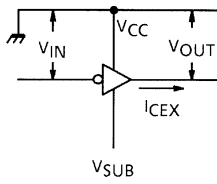
## ELECTRICAL CHARACTERISTICS (Ta = 25°C, VCC = 0 V)

| CHARACTERISTIC              |           | SYMBOL        | TEST CIR-CUIT | TEST CONDITION   | MIN       | TYP. | MAX  | UNIT    |
|-----------------------------|-----------|---------------|---------------|--|-----------|------|------|---------|
| Output Leakage Current      |           | $I_{CEX}$     | 1             | $V_{OUT} = V_{GND} = -50 V$<br>$T_a = 85^\circ C$              | —         | —    | -100 | $\mu A$ |
| Output Saturation Voltage   |           | $V_{CE(sat)}$ | 2             | $V_{IN} = V_{IL, MAX.}$<br>$I_{OUT} = -100 mA$                 | —         | —    | -1.8 | V       |
|                             |           |               |               | $V_{IN} = V_{IL, MAX.}$<br>$I_{OUT} = -350 mA$                 | —         | —    | -2.0 |         |
| DC Current transfer Ratio   |           | $h_{FE}$      | 2             | $V_{CC} = 0 V, V_{CE} = 3 V$<br>$I_{OUT} = -350 mA$            | 1000      | —    | —    | —       |
| Input Voltage               | "H" Level | TD62786       | 4             | —  | -1.2      | —    | 0    | V       |
|                             |           | TD62787       |               |  | -1.6      | —    | 5.5  |         |
|                             | "L" Level | TD62786       |               |  | -30       | —    | -2.8 |         |
|                             |           | TD62787       |               |  | $V_{GND}$ | —    | -3.7 |         |
| Input Current               |           | $I_{IL}$      | —             | $V_{CC} = 5.5 V, V_{IN} = 0.4 V$                               | —         | —    | -0.4 | mA      |
| Clamp Diode Reverse Current |           | $I_R$         | —             | $V_R = V_{R, MAX.}, T_a = 85^\circ C$                          | —         | —    | 100  | $\mu A$ |
| Clamp Diode Forward Voltage |           | $V_F$         | —             | —  | —         | —    | 2.0  | V       |
| Turn-On Delay               |           | $t_{ON}$      | 5             | $V_{OUT} = -50 V, R_L = 163 \Omega$<br>$C_L = 15 pF$<br>(Note) | —         | 0.2  | —    | $\mu s$ |
| Turn Off Delay              |           | $t_{OFF}$     |               |  | —         | 1.0  | —    |         |

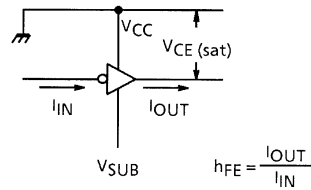
Note:  $V_{OUT} = -35 V, R_L = 116 \Omega$  for Type-F

**TEST CIRCUIT**

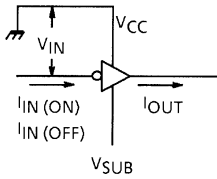
**1.  $I_{CEX}$**



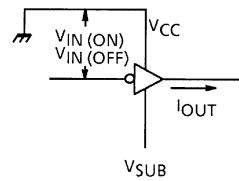
**2.  $V_{CE(sat)}$ ,  $h_{FE}$**



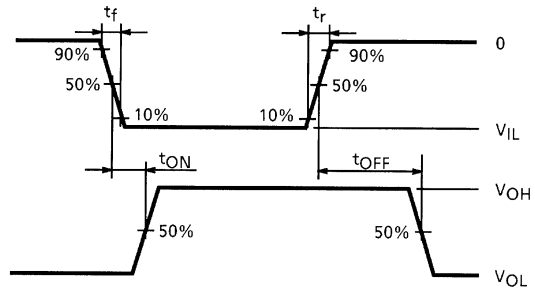
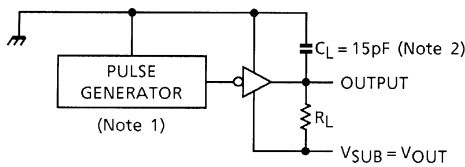
**3.  $I_{IN(ON)}$ ,  $I_{IN(OFF)}$**



**4.  $V_{IN(ON)}$ ,  $V_{IN(OFF)}$**



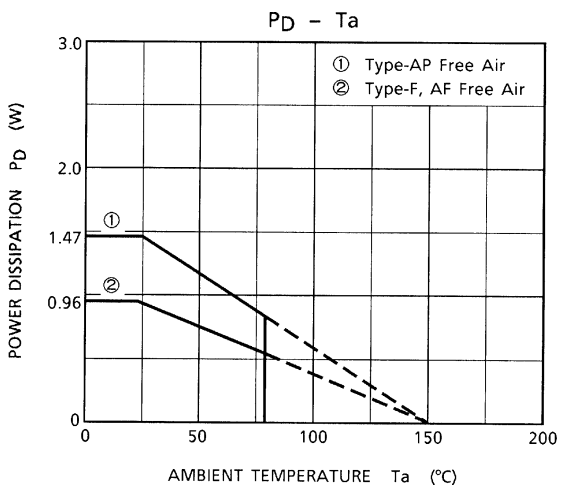
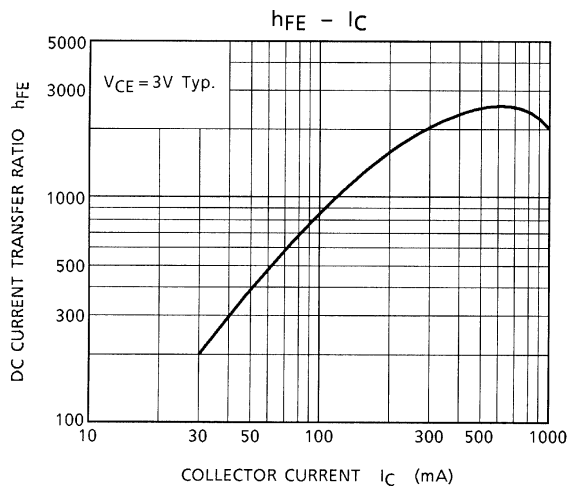
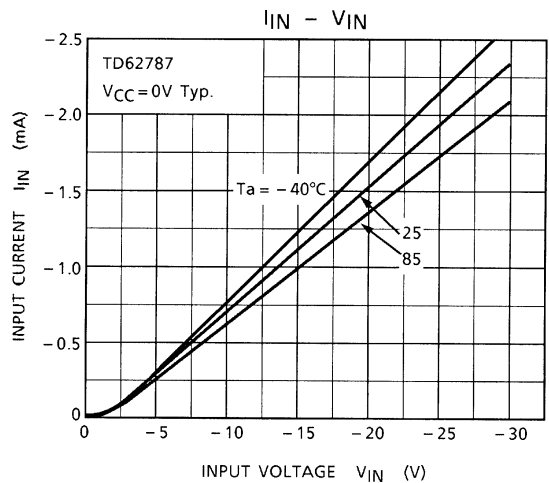
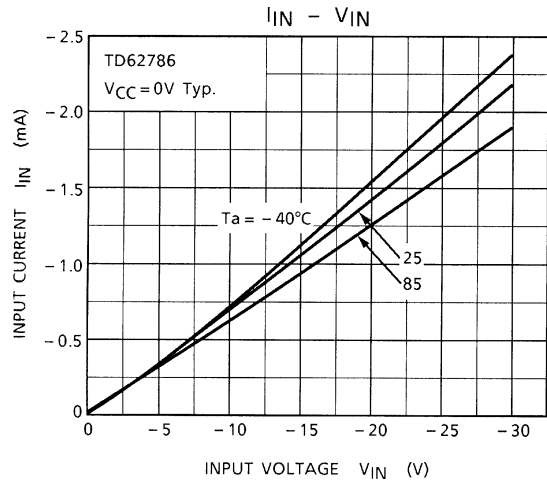
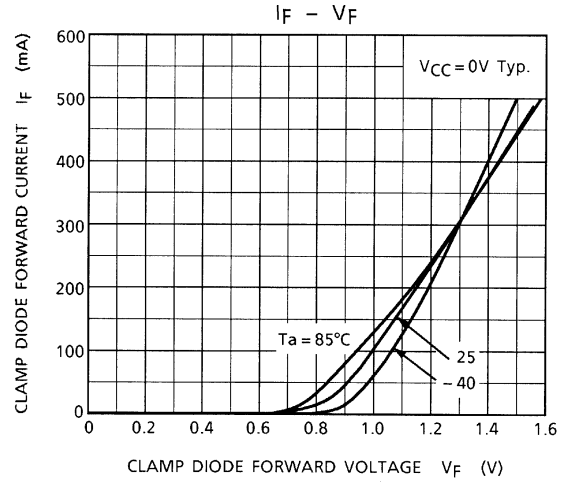
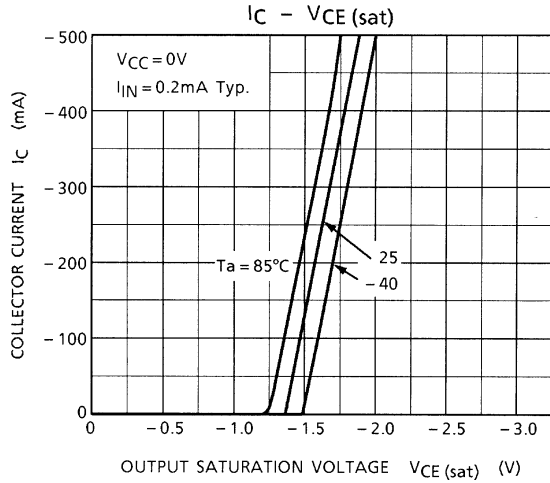
**5.  $t_{ON}$ ,  $t_{OFF}$**



Note 1: Pulse Width 50  $\mu$ s, Duty Cycle 10%  
 Output Impedance 50  $\Omega$ ,  $t_r \leq 10$  ns,  $t_f \leq 5$  ns  
 Note 2:  $C_L$  includes probe and jig capacitance.

**PRECAUTIONS for USING**

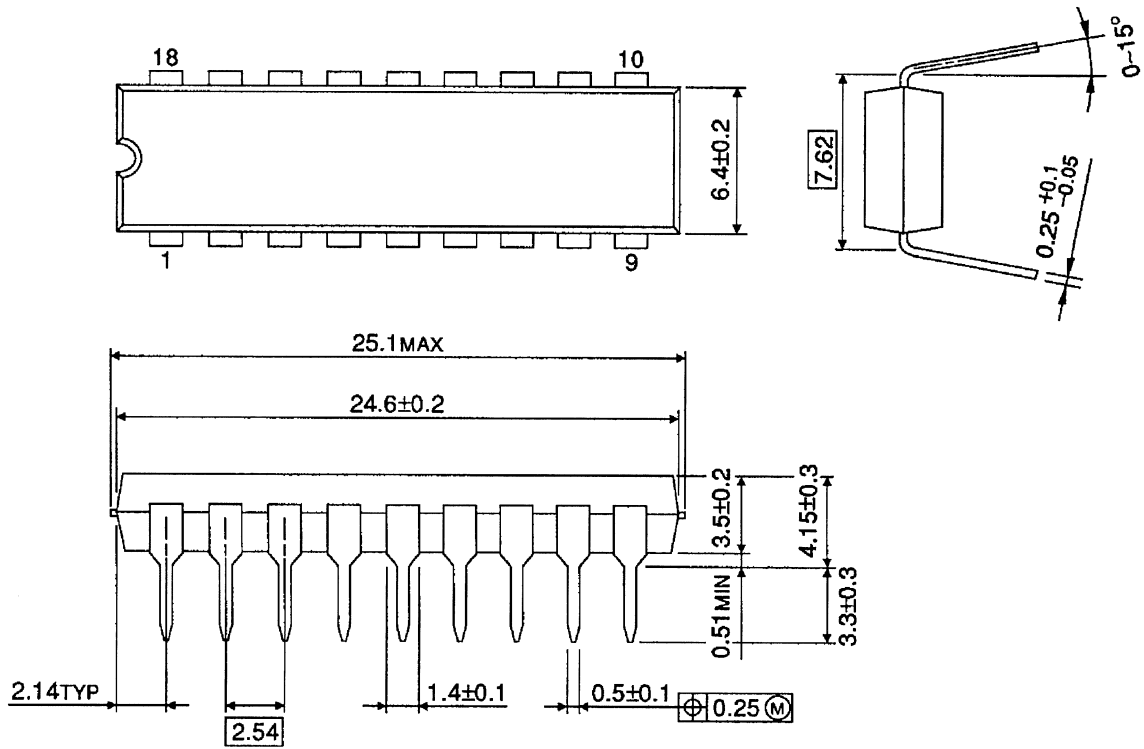
This IC does not integrate protection circuits such as overcurrent and overvoltage protectors. Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC. Utmost care is necessary in the design of the output line, VCC and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.



**PACKAGE DIMENSIONS**

DIP18-P-300-2.54D

Unit: mm

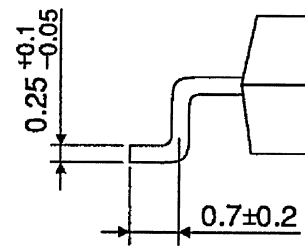
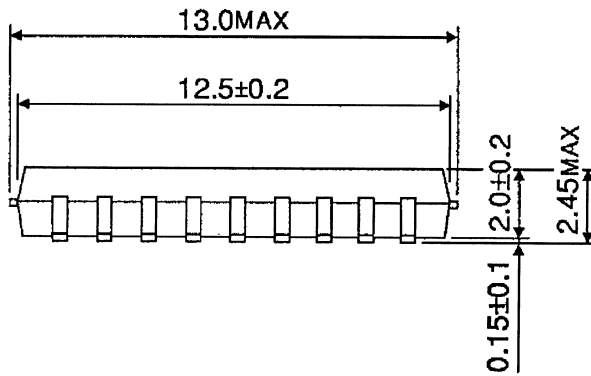
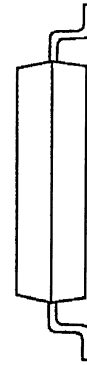
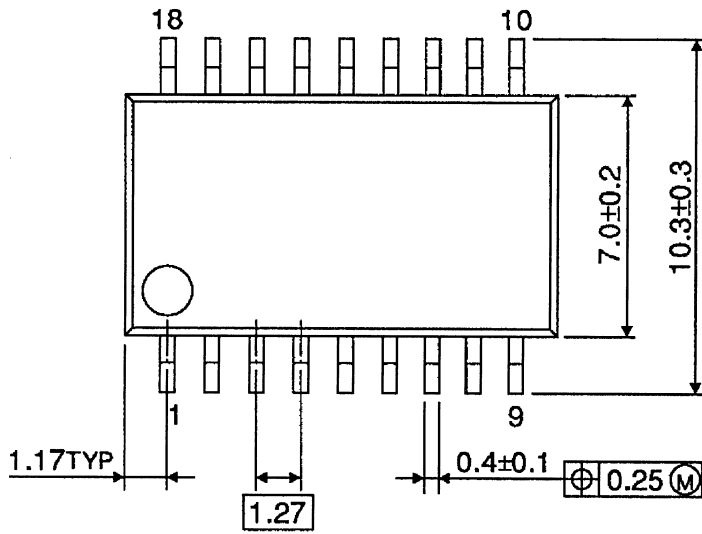


Weight: 1.47 g (Typ.)

## PACKAGE DIMENSIONS

SOP18-P-375-1.27

Unit: mm



Weight: 0.41 g (Typ.)

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